

PREDICTING PHONON PROPERTIES FROM *AB-INITIO* MOLECULAR DYNAMICS AND NORMAL MODE DECOMPOSITION

Jason Larkin¹, Alex Massicotte¹, Alan J.H. McGaughey¹, Wissam A. Al-Saidi²

¹Department of Mechanical Engineering, Carnegie Mellon University, ²Department of Chemistry, University of Pittsburgh

Supported by AFSOR FA95501010098 (2010 YIP)

Background

- Thermal conductivity of Si (dielectric) is determined by phonons:

$$\kappa = \frac{1}{V} \sum_i c_v(\omega_i) v_g^2(\omega_i) \tau_i(\omega_i)$$

- Classical molecular dynamics simulation over-predicts experiment at **300K**:

$$\kappa_{SW} \sim 400 \text{ W/m-K}^1$$

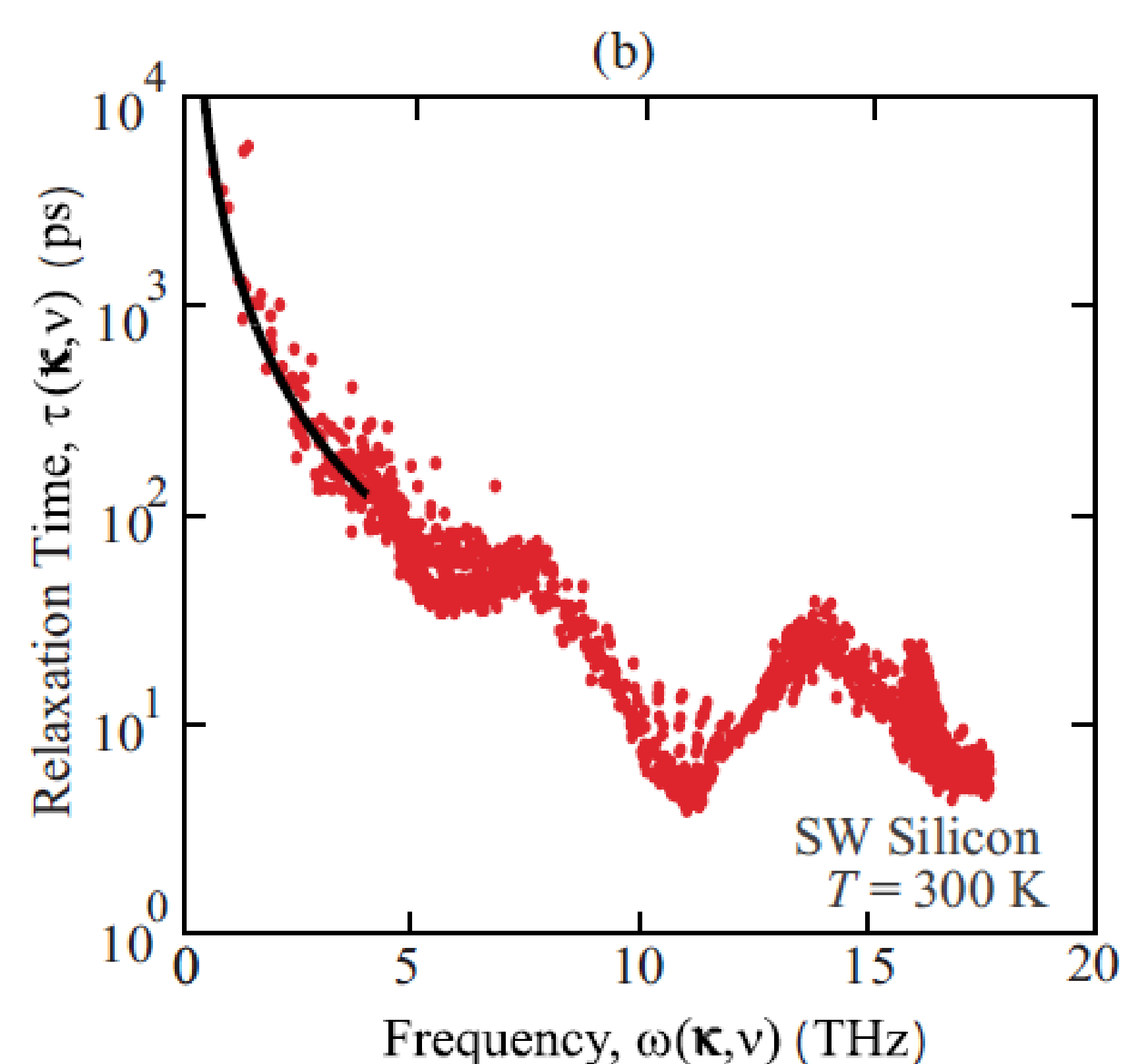
$$\kappa_{EXP} \sim 130 \text{ W/m-K}$$

- *Ab-Initio* molecular dynamics can model Silicon accurately to measure phonon properties:

$$\omega_i, \tau_i(\omega_i), v_g(\omega_i)$$

- Phonon lifetime/mean free path:

$$\Lambda_i(\omega_i) = \tau_i(\omega_i) |v_g(\omega_i)|$$



Normal Mode Decomposition

- Atomic motion is a superposition of normal modes:

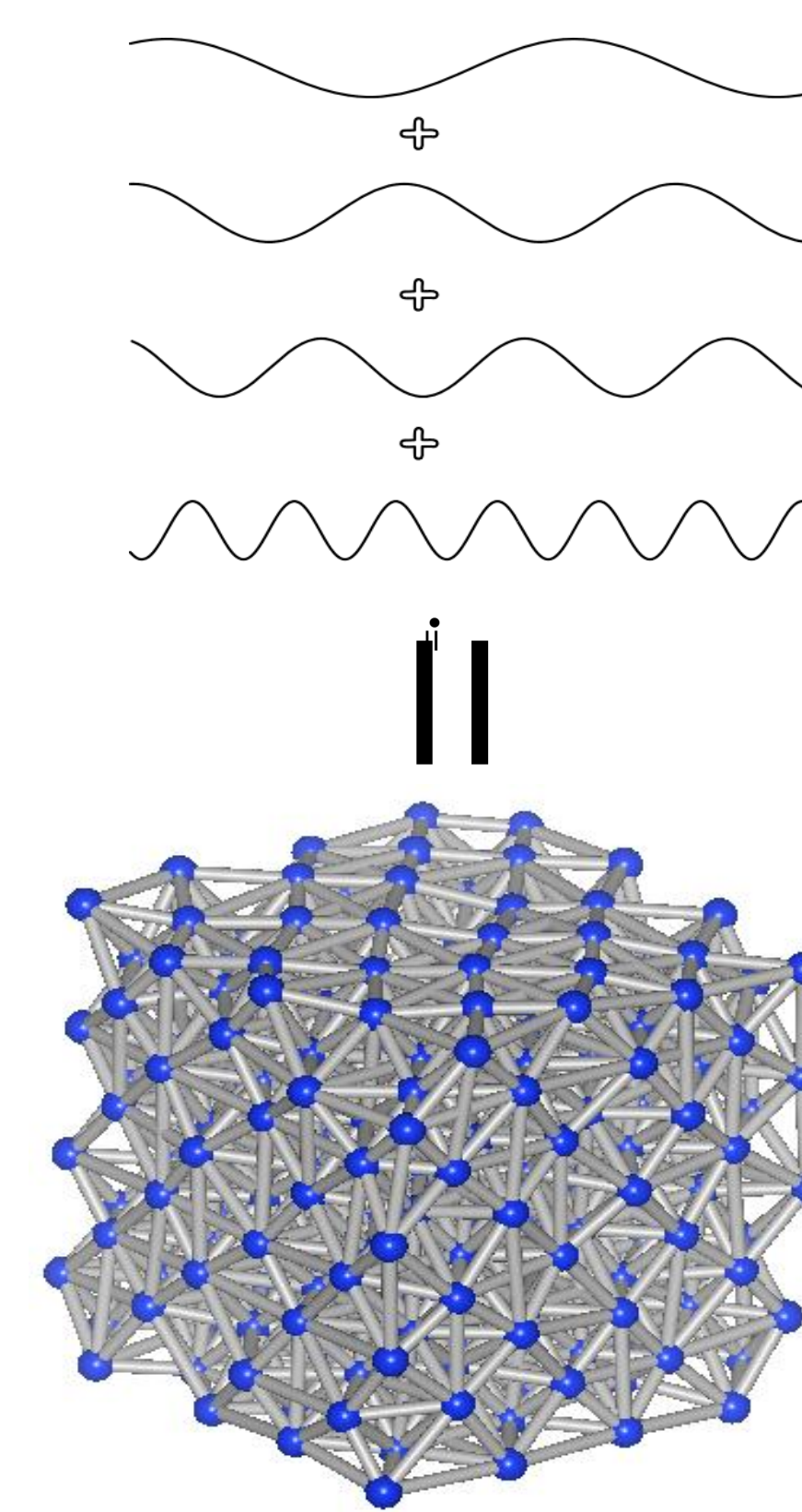
$$\dot{u}_\alpha \begin{pmatrix} l \\ b \end{pmatrix}; t = \frac{1}{\sqrt{Nm_b}} \sum_{\kappa', \nu} e \begin{pmatrix} \kappa' b \\ \nu \alpha \end{pmatrix} \exp \left[i \mathbf{\kappa} \cdot \mathbf{r}_0 \begin{pmatrix} l \\ 0 \end{pmatrix} \right] \dot{q} \begin{pmatrix} \kappa' \\ \nu \end{pmatrix}; t$$

NEED:

- Equilibrium positions

- Eigenvectors from Lattice Dynamics

- Velocities from Molecular Dynamics

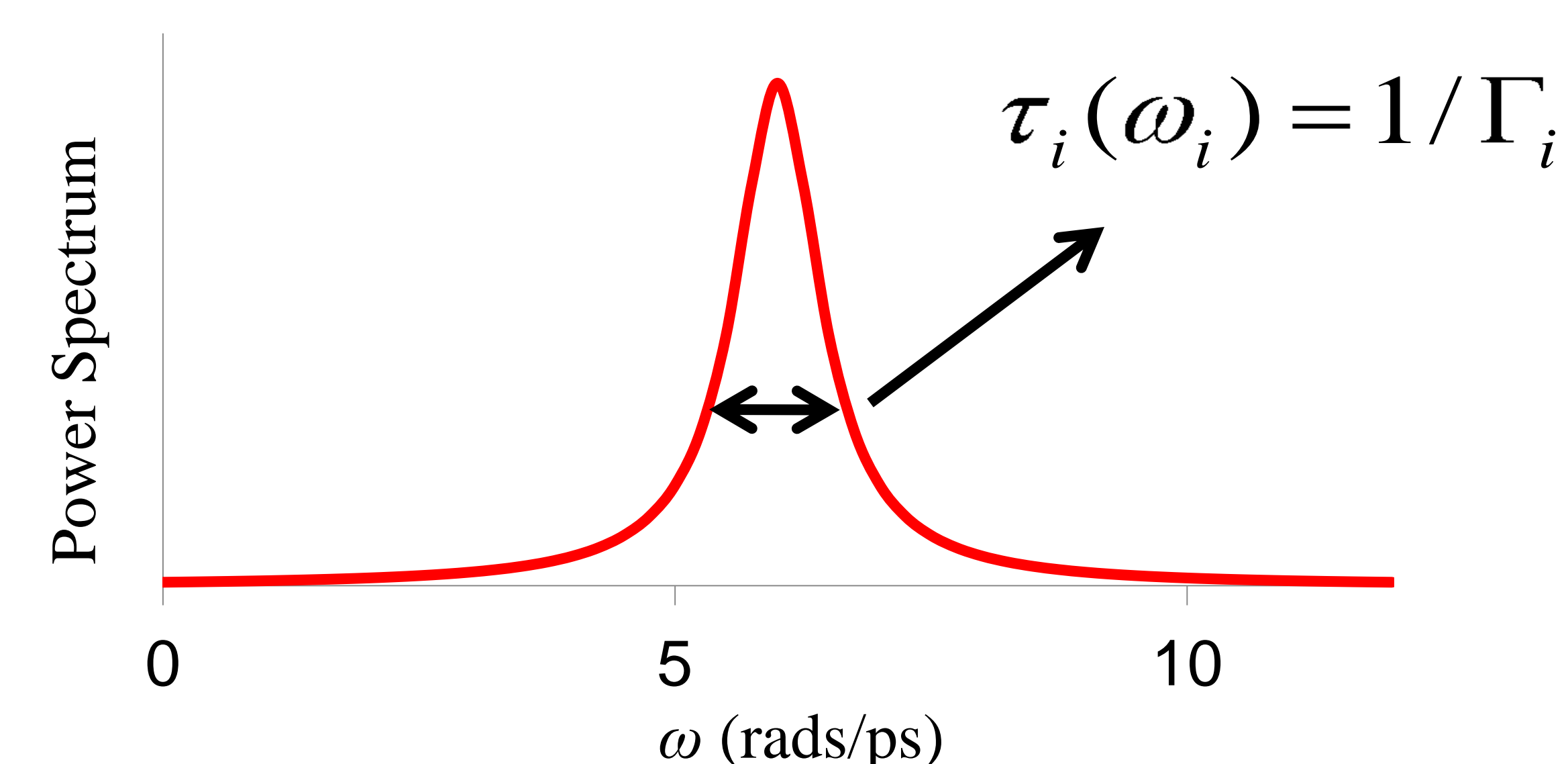


- Map atomic motion onto normal modes:

$$\dot{q} \begin{pmatrix} \kappa \\ \nu \end{pmatrix}; t = \sum_{\alpha, b, l} \sqrt{\frac{m_b}{N}} \dot{u}_\alpha \begin{pmatrix} l \\ b \end{pmatrix}; t e^* \begin{pmatrix} \kappa b \\ \nu \alpha \end{pmatrix} \exp \left[i \mathbf{\kappa} \cdot \mathbf{r}_0 \begin{pmatrix} l \\ 0 \end{pmatrix} \right]$$

- Power spectrum of normal modes:

$$\Phi \begin{pmatrix} \kappa \\ \nu \end{pmatrix}; \omega = \left| \int_{-\infty}^{\infty} \dot{q} \begin{pmatrix} \kappa \\ \nu \end{pmatrix}; t \exp(i\omega t) dt \right|^2$$



Normal Mode Spectral Energy is Lorentzian with peak at phonon frequency.

Ab-Initio Molecular Dynamics

Density Functional Theory:

$$\hat{H}\Psi = \left[\sum_i^N -\frac{\hbar^2}{2m} \nabla_i^2 + \sum_i^N V(\vec{r}_i) + \sum_{i<j}^N U(\vec{r}_i, \vec{r}_j) \right] \Psi = E\Psi$$

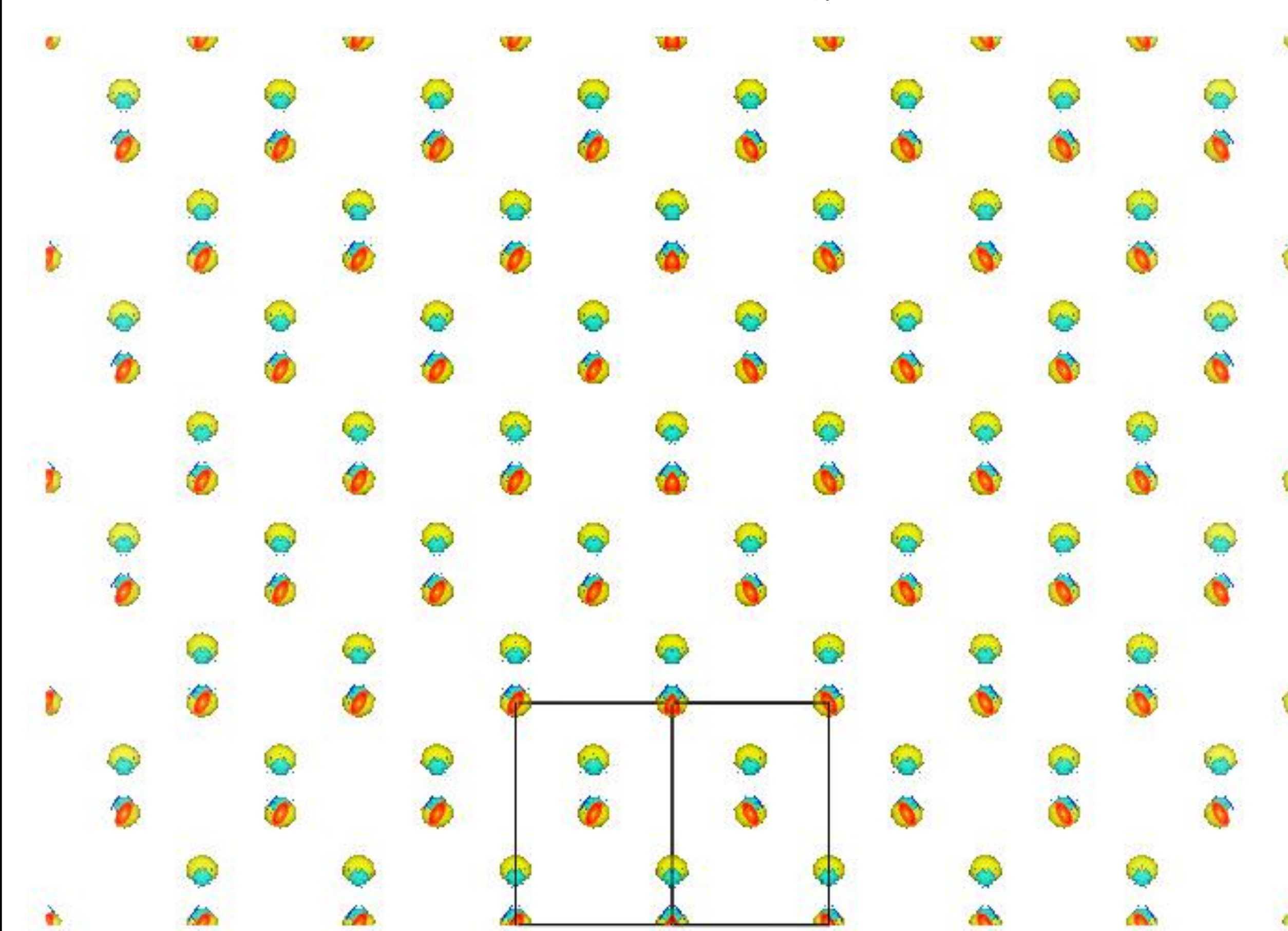
Molecular Dynamics:

$$\vec{F} = m\vec{a} = -\nabla E = \left\langle \psi \left| \frac{\partial \hat{H}}{\partial \vec{R}} \right| \psi \right\rangle$$

CP2K²:

- Used 128 CPU on Diamond and Garnet
- Mixed **Gaussian** and **Plane Wave** code:

$$\psi_{nk}(\vec{r}) \propto \exp(-\alpha \vec{r}^2) \propto \sum_k C_k \exp(i\vec{k} \cdot \vec{r})$$



Si electronic kinetic energy density calculated using Density Functional Theory

Simulation Expense

CP2K

- 3 steps/min/128cpu =

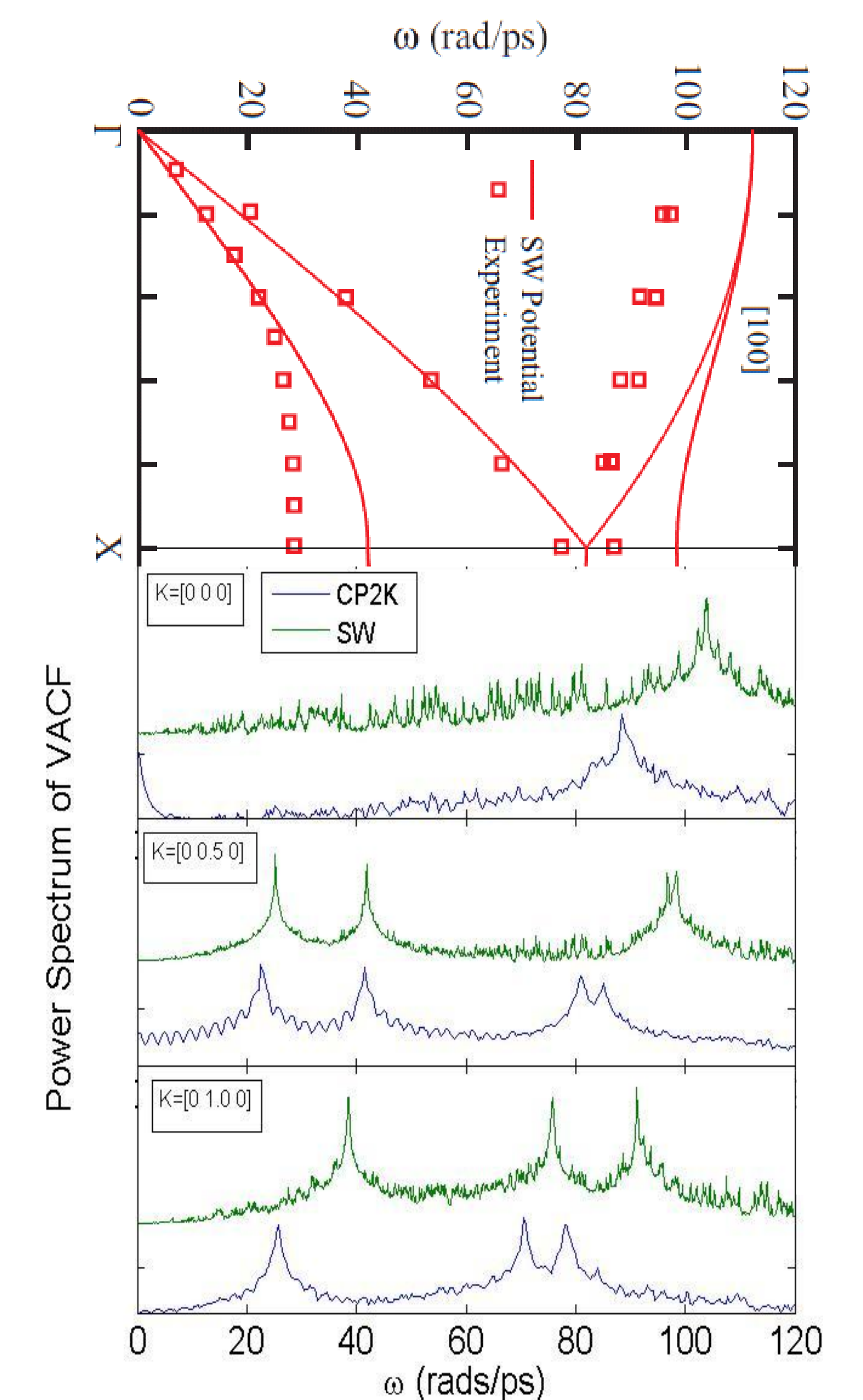
0.023 steps/min/cpu

Stillinger-Weber

- 6E4 steps/min/4 cpu =

15000 steps/min/cpu

Power Spectrum



Vibrational power spectrum for Si from CP2K and Stillinger-Weber with matching dispersion curve.

¹E. S. Landry, Ph.D. Thesis, Carnegie Mellon University 2009

²<http://cp2k.berlios.de/>